NSN 5961-00-449-7030

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass and metal
Overall Length:
0.962 inches
Terminal Length:
0.360 inches
Overall Height:
0.340 inches
Overall Width:
0.500 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
4.00 amperes forward current, total rms preset
Power Rating Per Characteristic:
16.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius case
Special Features:
Design analysis; junction pattern arrangement: pnp
Nuclear Hardness Critical Feature:
Hardened
Terminal Type And Quantity:
1 case and 2 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
File:

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